DT200ID

Reduced size, ultra-stable, high precision (ppm class) fluxgate technology DT Series current transducer for isolated DC and AC current measurement up to 200Arms



Features

DANI/ENSE

- Fluxgate, closed loop compensated technology with fixed excitation frequency and second harmonic zero flux detection for best in class accuracy and stability
- 2 MHz high frequency bandwidth
- Excellent linearity, better than 1 ppm
- Industry standard DSUB 9 pin connection
- Green diode for normal operation indication
- Large aperture Ø20.7mm for cables and bus bars
- Weighs only 0.15 kg

Applications

- Optimized for space constraint applications
- MPS for particles accelerators
- Gradient amplifiers for MRI devices
- Stable power supplies
- Precision drives
- Batteries testing and evaluation systems
- Power measurement and power analysis
- Variable speed drives
- Calibration unit

Specification highlights	Symbol	Unit	Min	Тур	Max
Nominal continuous primary AC current	I _{PN} AC	Arms			200
Nominal continuous primary DC current	I _{PN} DC	А	-200		200
Measuring range	Î _{PM}	А	-285		285
Primary / secondary ratio	n1 : n2		1:1000		1:1000
Linearity error	ε _L	ppm	-1	0.4	1
Offset current (including earth field)	I _{OE}	ppm	-25		25
DC-10Hz Overall accuracy @25°C (= $\mathcal{E}_L + I_{OE}$)	acc8	ppm	-26		26
Bandwidth	f(±3dB)	kHz		2000	
AC typical gain error 10Hz to 5kHz	εg	%		±0.01	
Operating temperature range	Та	°C	-40		85
Power supply voltages	Uc	V	±14.25		±15.75

All ppm (or %) values refer to nominal current



DT200ID

Electrical specifications at Ta=23°C, supply voltage = ± 15V unless otherwise stated

Parameter		Symbol	Unit	Min	Тур.	Мах	Comment
Nominal continuous	orimary AC current	I _{PN} AC	Arms			200	Refer to fig. 1 & 2 for derating
Nominal continuous	primary DC current	I _{PN} DC	А	-200		200	Refer to fig. 1 for derating
Measuring range		I _{PM}	А	-285		285	Refer to fig. 1 & 2 for derating
Overload capacity		Î _{OL}	А	-1000		1000	Non-measured, 100ms
Nominal secondary c	urrent	I _{SN}	mA	-200		200	At nominal primary DC current
Primary / secondary	ratio			1:1000		1:1000	
Measuring resistance	;	R _M	Ω	0	5		Refer to fig. 1 for details
Linearity error		<u>د</u>	ppm	-1	0.4	1	ppm refers to nominal current
			μA	-0.2	0.08	0.2	μA refers to secondary current
Offset current		I _{OE}	ppm	-25		25	ppm refers to nominal current
			μΑ	-5		Э	µA refers to secondary current
+ IOE)	suracy @25°C (= EL	acc8	ppm	-26		26	ppm refers to nominal DC current
Offset temperature co	pefficient	TCIOE	ppm/K	-0.2	0.1	0.2	ppm refers to nominal current
			μΑ/Κ	-0.04	0.02	0.04	µA refers to secondary current
Bandwidth		f(±3dB)	kHz		2000		Small signal, graphs figure 3
Amplitude error					0.01%		
		8G	%		1%		See notes in fig. 3
	100KHZ - 1000KHZ				10%		
Dhace chift					30%		
Phase shill	1002 – 3K02 5kHz – 100kHz				0.01° 10		
	100kHz - 1000kHz	θ	0		ı 100		See notes in fig. 3
	1000kHz - 2000kHz				40°		
Response time to a s	tep current IPN	tr @ 90%	μs		1		
RMS noise	0.1Hz - 10Hz				0.01	0.03	
	0.1Hz - 100Hz				0.2	0.5	
	0.1Hz - 1kHz	noise	ppm RMS		0.3	0.7	ppm RMS refers to nominal cur-
	0.1Hz - 10kHz				0.5	1	i cint
	0.1Hz - 100kHz				3.3	6	
Peak-to-peak noise	0.1Hz - 10Hz				0.2	0.3	
	0.1Hz - 100Hz				0.8	1	nom poak to poak refers to nomi
	0.1Hz - 1kHz	noise	ppm p-p		1.6	2	nal current
	0.1Hz - 10kHz				2.5	4	
	0.1HZ - 100KHZ				25	40	
Fluxgale excitation in	equency	TExc	KHZ		31.25		
Induced rms voltage	on primary conductor		μV rms			5	
Power supply voltages		Uc	V	±14.25		±15.75	
Positive current consumption		lps	mA		40		Add Is (if Is is positive)
Negative current consumption		Ins	mA		35		Add Is (if Is is negative)
Operating temperature range		Та	°C	-40		85	
Stability							
Offset stability over			ppm/month	-0.1		0.1	ppm refers to nominal current
time				-0.02		0.02	µA refers to secondary current
Impact of external ma	agnetic field		ppm/mT uA/mT	-4 -0.8	1 02	4 0.8	ppm reters to nominal current
Offset change with p	ower supply voltages		ppm/mV	-0.0	0.0013	0.0	ppm refers to nominal current
changes			μA/mV		0.0003		µA refers to secondary current

Measurement resistor RM and ambient temperature derating (Fig. 1)

Maximum measurement resistor vs. ambient temperatures



Frequency and ambient temperature derating (Fig. 2)



Maximum primary current Arms

Frequency characteristics (Fig. 3)

Typical Amplitude / Phase response



Precision – Innovation www.danisense.com



Isolation specifications

Parameter	Unit	Value
Clearance	mm	11.5
Creepage distance	mm	11.5
Rms voltage for AC isolation test, 50/60 Hz, 1 min - Between primary and (secondary and shield)	kV	5.7
Impulse withstand voltage (1.2/50µs)	kV	10.4
Rated rms isolation voltage		
reinforced isolation, overvoltage category III, Pollution de according to	gree 2 V	
- IEC	61010-1	300
- EN5	50780	600

Absolute maximum ratings

Parameter	Unit	Max	Comment	
Primary	А	1000	Maximum 100ms	
Power supply	V	±16.5		

Environmental and mechanical characteristics

Parameter	Unit	Min	Тур	Мах	Comment		
Altitude	m			2000			
Usage					Designed for indoor use		
Transient voltages					Up to overvoltage category III		
Polution Degree				2			
Ambient operating tempera- ture range	°C	-40		85			
Storage temperature range	°C	-40		85			
Relative humidity	%	20		80	Non-condensing		
Mass	kg		0.15				
Connections	Power supplies: D-SUB 9 pins male						
	EMC: IEC 61326-1:2013-2021 Safety: IEC 61010-2-30 and IEC 61010-1:2010 3rd Edition Standards Random vibration test: IEC 60068-2-64:2008 Shock test: IEC 60068-2-27:2009						
Standards							
Transport test: IEC				60068-2-64:2008			

DANIJENSE

DT200ID



(general tolerance 0.3mm unless otherwise stated)

DSUB pin layout

Standard DSUB-9 current output



pins are shorted. Status pin properties. Forward direction pin 8 to pin 3
Maximum forward current 10mA Maximum forward voltage 60V
Maximum reverse voltage 5V



Positive current direction

Mounting instructions

Is identified by an arrow on the transducer body

Base plate mounting:

2 x M4 - slotted holes

Suggested fastening torque: 5.5 Nm



Declaration of Conformity

Danisense A/S Malervej 10 DK-2630 Taastrup Denmark

Declares that under our sole responsibility that this product is in conformity with the provisions of the following EC Directives, including all amendments, and with national legislation implementing these directives:

Directive 2014/30/EU

Directive 2014/35/EU

And that the following harmonized standards have been applied

EN 61010-1 (Third Edition):2010, EN 61010-1:2010/A1:2019

EN 61010-2-030:2021/A11:2021

EN 61326-1:2013

All DANISENSE products are manufactured in accordance with RoHS directive 2011/65/EU. Annex II of the RoHS directive was amended by directive 2015/863 in force since 2015, expanding the list of 6 restricted substances (Lead, Hexavalent Chromium, PBB, PBDE and Cadmium)

Danisense follows the provision in EN 63000:2018

Nourl E

Place

Taastrup, Denmark

Henrik Elbæk

Date 2022-03-15